



Upgraded G-optk program for electron gun characterization

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ABSTRACT

The generalized trajectory theory (the G-optk program) has been extended in order to make the method applicable to electron guns with curved and/or asymmetric cathodes. The object-image analysis mode has also been added. Enhanced capability of the upgraded G-optk program was demonstrated by applying the program to three electron optical systems: (a) the point cathode gun, (b) the hairpin-type cathode gun, and (c) the LEEM objective lens. The Canonical Mapping Transformation (CMT) diagrams were calculated both by direct ray tracing and by the upgraded G-optk program. In each case, it was found that the upgraded program reproduces well the results obtained by ray tracing. The generalized trajectory method has several advantages over direct ray tracing, such as substantially lighter calculation load and easy interpretation of the calculation results in terms of the optical parameters.

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1. Introduction

The characterization of cathode rays inside electron guns is in principle possible by use of the trajectory theory (the paraxial trajectory and aberration theory), as opposed to conventional direct ray tracing. The key to the successful treatment of cathode rays with large inclination angles lies in an accurate reproduction of parabolic-shape ray paths in accelerating field in front the cathode. Several schemes were proposed to represent parabolic rays within the paraxial trajectory scheme [1,2].

The present authors have found that a simple mathematical relation exists between the ray condition (position and slope) on the cathode surface and that at the crossover plane (see Fig. 1) [3]. If a 2D–2D mapping, $(\xi_x, u_x = \sin \alpha) \geq (\eta_{cx}, v_x = \sin \beta)$, is considered, it must satisfy the canonical condition and can be characterized by a set of transformation parameters. We shall designate the mapping as the CMT diagram. A scrutinized review of the conventional trajectory theory has revealed that mapping can be approximated by third-order polynomials [4]:

$$\eta_{cx}(\xi_x, u_x) = f \sqrt{\Phi_0 / \Phi_1} u_x + \sum_{k+l=3} a_{kl} \xi_x^k u_x^l \quad (1a)$$

$$v_x(\xi_x, u_x) = -\xi_x / f + m u_x + \sum_{k+l=3} b_{kl} \xi_x^k u_x^l \quad (1b)$$

where f , m , a_{kl} and b_{kl} are optical parameters defined by these equations that stand for electron gun focal length, modified angular magnification and aberration coefficients, respectively. For the

evaluation of the polynomial coefficients, a method very similar to that used in the conventional trajectory theory can be used. The mathematical expression for the mapping is given by

$$\begin{pmatrix} \eta_{cx} \\ v_x \end{pmatrix} = \begin{pmatrix} g(z_c) & h(z_c) \\ g'(z_c) & h'(z_c) \end{pmatrix} \left\{ \begin{pmatrix} \xi_x \\ u_x \end{pmatrix} + \frac{1}{\sqrt{2me\Phi_0}} \begin{pmatrix} -\frac{\partial V^I}{\partial u_x} \\ \frac{\partial V^I}{\partial \xi_x} \end{pmatrix} \right\}, \quad (2)$$

where $V^I(\xi_x, u_x)$ represents the aberration integral arising from the fourth-order Lagrangian terms in the action integral, of which the formula is given by Eq. (13) in Ref. [4]. The principal paraxial trajectories are represented by $g(z)$ and $h(z)$.

An apparently trivial calculus difference from the conventional theory consists of replacing the trigonometric function $\tan$ with $\sin$ in the trajectory slope definition. The physical significance behind the choice of $\sin$ is that in assigning the paraxial trajectory to the cathode ray, the transverse momentum of the ray is considered more important, rather than its slope. Fig. 2 shows how the paraxial trajectories are assigned to a parabolic cathode ray in each case. In the proposed method a trajectory that has the same transverse momentum as the cathode ray is adopted in the paraxial approximation.

We reported in the previous conference (CPO-7, Cambridge UK) the implementation of the generalized trajectory theory in the G-optk program for electron gun characterization [5]. The new approach can offer a suite of optical parameters (the coefficients), including aberration coefficients, to define the electron gun characteristics. However, the applicability of the program has so far been limited to electron guns that have flat cathodes; the trajectory theory can perform calculation only from one reference plane to the other plane. It is desirable to lift the limitation and enable the G-optk program to deal with a wider range of electron guns.

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